



Form PTO-1449

INFORMATION DISCLOSURE CITATION  
IN AN APPLICATION  
(Use several sheets if necessary)

Doc. No. (Optional)  
CS-01-193

Applicant  
Tze Ho Chan et al.

Filing Date  
10/30/03

Application Number  
10/697,746

Group Art Unit

U. S. PATENT DOCUMENTS												
EXAMINER INITIAL	DOCUMENT NUMBER						DATE	NAME	CLASS	SUBCLASS	FILED DATE IF APPROPRIATE	
an	6	3	5	8	8	1	9	3/19/02	Shelton et al.	438	433	12/15/98
an	5	9	1	8	1	1	6	6/29/99	Chittipeddi	438	199	5/9/97
an	6	0	6	3	6	7	0	5/16/00	Lin et al.	438	275	4/15/98
an	6	3	4	2	4	3	8	1/29/02	Yu et al.	438	520	11/6/98
an	5	3	5	6	8	2	1	10/18/94	Naruse et al.	437	34	8/12/93
an	6	3	7	6	3	2	3	4/23/02	Kim et al.	438	373	4/4/01

FOREIGN PATENT DOCUMENTS													
	DOCUMENT NUMBER							DATE	COUNTRY	CLASS	SUBCLASS	Translation	
												YES	NO

OTHER DOCUMENTS (Including Author, Title, Date, Portion of Pages, Etc.)									
an	CS-01-093	Serial No. 10/266,425, Filed 10/08/02 to							
		Chew-Hoe Ang et al., "Dual Si-Ge Polysilicon							
an		Gate with Different Ge Concentrations for							
		CMOS Device Optimization"							

EXAMINER

DATE CONSIDERED  
11-24-04

EXAMINER: Initial if citation considered, whether or not citation is in conformance with MPEP § 609; Draw line through citation if not in conformance and not considered. Include copy of this form with next communication to the applicant.